

## SEMiSTART

### Antiparallel thyristors for softstart

#### SKKQ 800

#### Features

- Compact design
- Thyristor with amplifying gate
- Pressure contact technology

#### Typical Applications\*

- Soft Starters

#### Remarks

- Please note: This module has no soft mold protection around the chip. It is therefore susceptible to environmental influences (dust, humidity, etc.). The humidity test according to IEC60068-2-67 is not passed by this product.
- Recommendation: The devices should be installed in control cabinets of IP54 degree of protection.

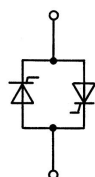
1)  $T_{vjmax}$  up to 150°C is allowable for overload conditions, max. time period for the overload condition is 20s.

#### Absolute Maximum Ratings

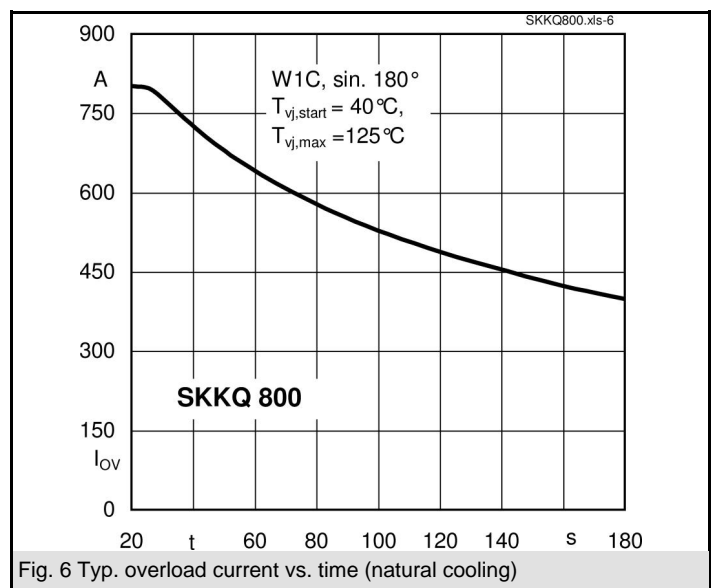
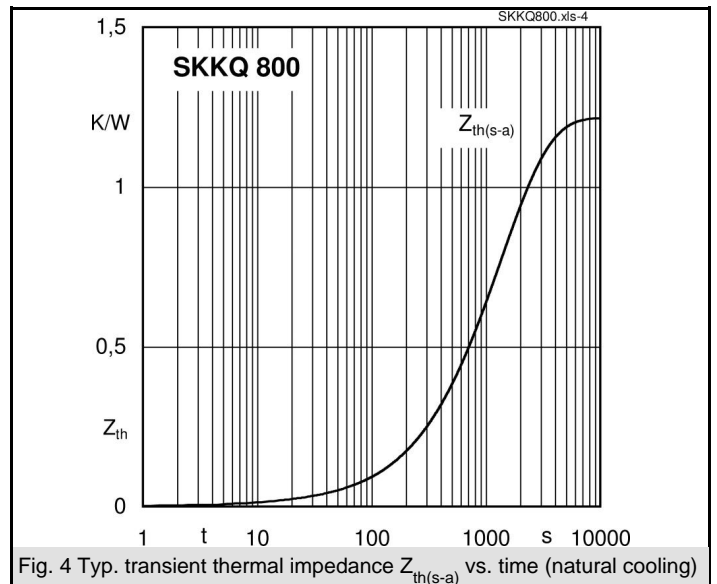
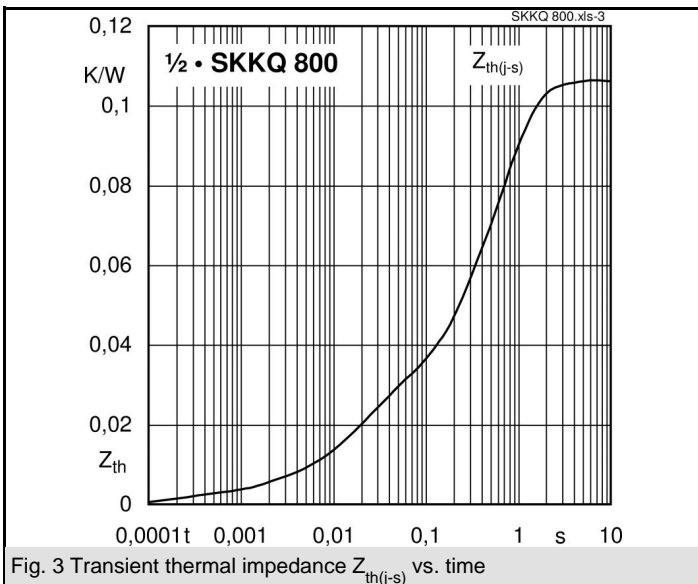
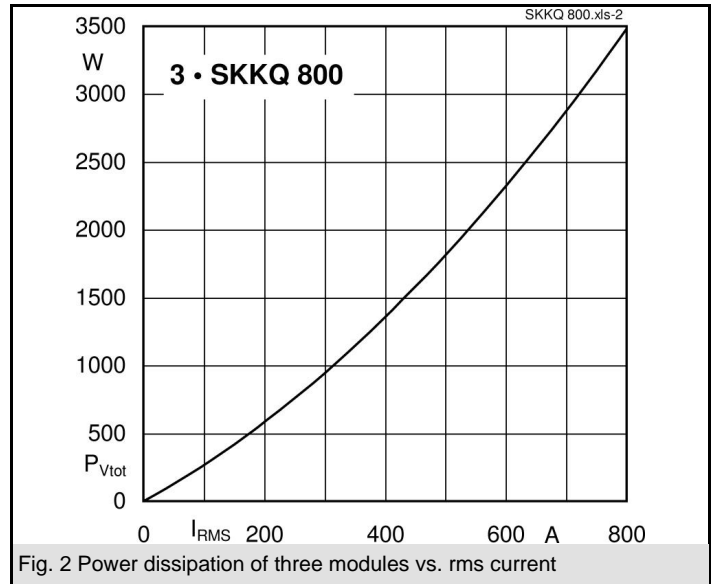
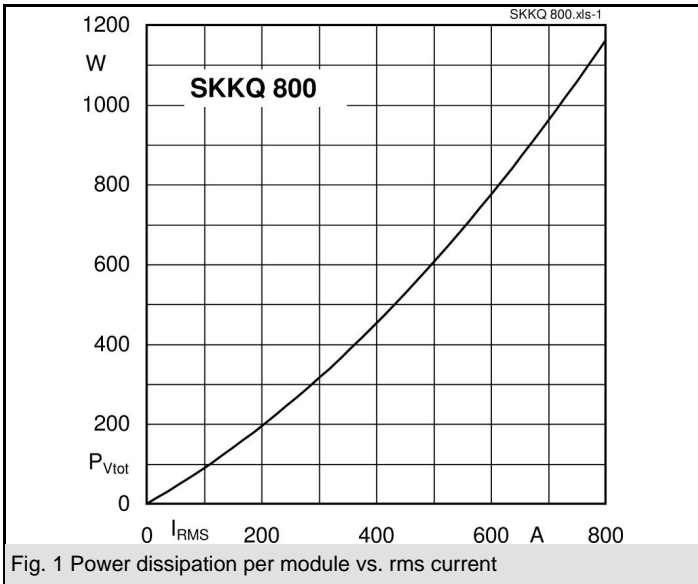
Symbol	Conditions	Values	Units
$I_{overload}$	W1C; sin. 180°; 20 sec.; $T_{vjmax} = 150\text{ °C}$ ; $T_{vjstart} = 40\text{ °C}$	800	A
$I_{TSM}$	$T_{vj} = 25\text{ °C}$ ; 10 ms	5700	A
	$T_{vj} = 125\text{ °C}$ ; 10 ms	5200	A
$I^2t$	$T_{vj} = 25\text{ °C}$ ; 8,3 ... 10 ms	162000	A <sup>2</sup> s
	$T_{vj} = 125\text{ °C}$ ; 8,3 ... 10 ms	135000	A <sup>2</sup> s
SKKQ 800/14			
$V_{RSM}$		1500	V
$V_{RRM}; V_{DRM}$		1400	V
SKKQ 800/18			
$V_{RSM}$		1900	V
$V_{RRM}; V_{DRM}$		1800	V
$T_{vj}$		-40 ... +125 <sup>1)</sup>	°C
$T_{stg}$		-40 ... +125	°C

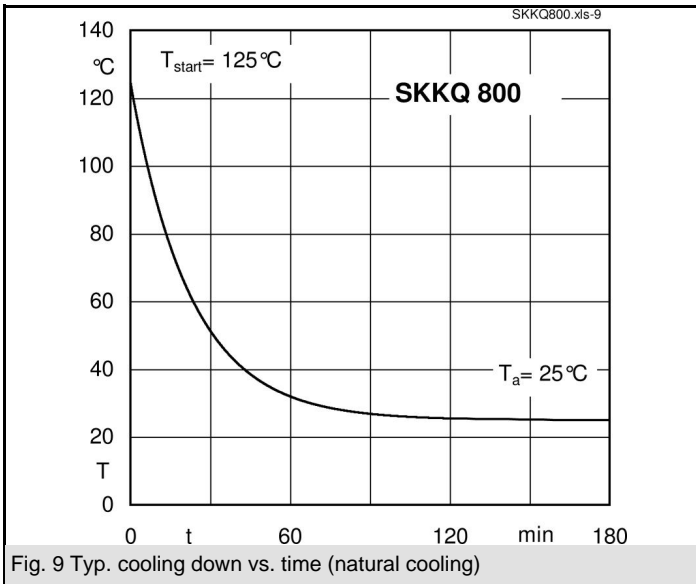
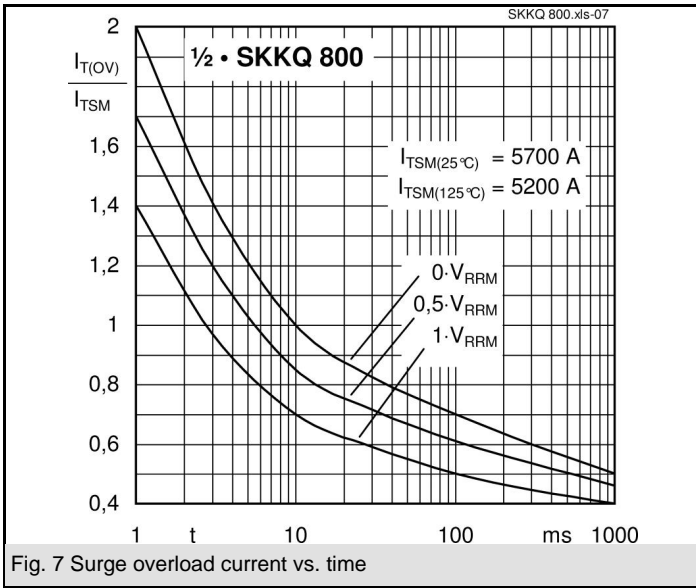
#### Characteristics

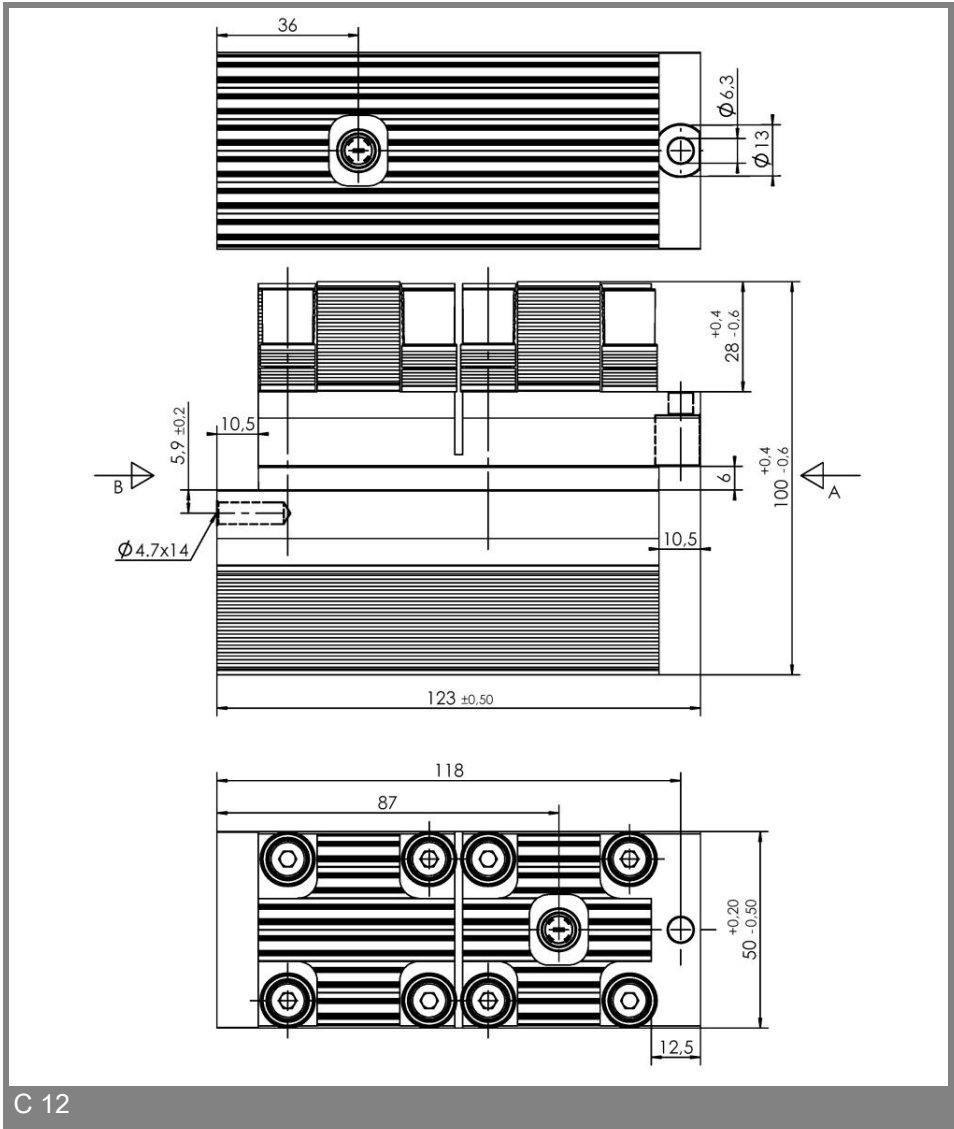
Symbol	Conditions	min.	typ.	max.	Units
$V_T$	$T_{vj} = 25\text{ °C}$ ; $I_T = 1000\text{ A}$			1,9	V
$V_{T(TO)}$	$T_{vj} = 125\text{ °C}$			0,9	V
$r_T$	$T_{vj} = 125\text{ °C}$			0,8	mΩ
$I_{DD}; I_{RD}$	$T_{vj} = 125\text{ °C}$ ; $V_{RD} = V_{RRM}$ ; per module			80	mA
$t_{gd}$	$T_{vj} = 25\text{ °C}$ ; $I_G = 1\text{ A}$ ; $di_G/dt = 1\text{ A}/\mu\text{s}$		1		μs
$t_{gr}$	$V_D = 0,67 * V_{DRM}$		2		μs
$(dv/dt)_{cr}$	$T_{vj} = 125\text{ °C}$		1000		V/μs
$(di/dt)_{cr}$	$T_{vj} = 125\text{ °C}$ ; $f = 50 \dots 60\text{ Hz}$		125		A/μs
$t_q$	$T_{vj} = 125\text{ °C}$		150		μs
$I_H$	$T_{vj} = 25\text{ °C}$		150	400	mA
$I_L$	$T_{vj} = 25\text{ °C}$ ; $R_G = 33\text{ Ω}$		300	1000	mA
$V_{GT}$	$T_{vj} = 25\text{ °C}$ ; d.c.	2			V
$I_{GT}$	$T_{vj} = 25\text{ °C}$ ; d.c.	150			mA
$V_{GD}$	$T_{vj} = 125\text{ °C}$ ; d.c.			0,25	V
$I_{GD}$	$T_{vj} = 125\text{ °C}$ ; d.c.			10	mA
$R_{th(j-s)}$	cont.; per thyristor			0,106	K/W
$M_t$			5 ± 15%		Nm
m	approx.		1200		g
Case			C 12		



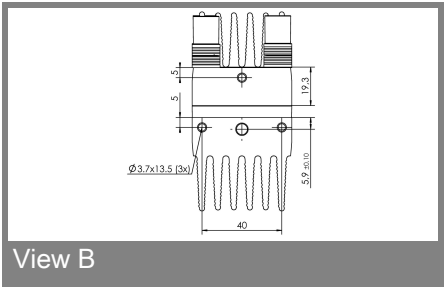
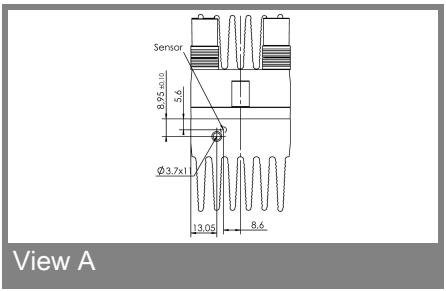
W1C







C 12



\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.